## NSN 5961-01-372-1071

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View Online at https://aerobasegroup.com/nsn/5961-01-372-1071 **Inclosure Material:** Ceramic **Overall Length:** Between 0.115 inches and 0.125 inches **Overall Height:** Between 0.046 inches and 0.054 inches Overall Width: Between 0.095 inches and 0.105 inches **End Application:** Milstar **Mounting Method:** Press fit **Features Provided:** Burn in and electrostatic sensitive and quality assurance level tx and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 95105-995-9501 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: